MLCC Medical Applications – MM Series

General Specifications





The AVX MM series is a multi-layer ceramic capacitor designed for use in medical applications other than implantable/life support. These components have the design & change control expected for medical devices and also offer enhanced LAT including reliability testing and 100% inspection.

APPLICATIONS

Implantable, Non-Life Supporting Medical Devices

· e.g. implanted temporary cardiac monitor, insulin pumps

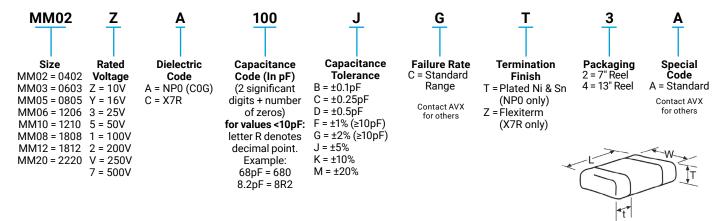
External, Life Supporting Medical Devices

· e.g. heart pump external controller

External Devices

· e.g. patient monitoring, diagnostic equipment

HOW TO ORDER



COMMERCIAL VS MM SERIES PROCESS COMPARISON

	Commercial	MM Series							
Administrative	Standard part numbers; no restriction on who purchases these parts	Specific series part number, used to control supply of product							
Design	Minimum ceramic thickness of 0.020" on all X7R product	Minimum ceramic thickness of 0.029" (0.74mm)							
Dicing	Side & end margins = 0.003" min	Side & end margins = 0.004" min Cover layers = 0.003" min							
Lot Qualification Destructive Physical Analysis (DPA)	As per EIA RS469	Increased sample plan – stricter criteria							
Visual/Cosmetic Quality	Standard process and inspection	100% inspection							
Application Robustness	Standard sampling for accelerated wave solder on X7R dielectrics	Increased sampling for accelerated wave solder on X7R and NP0 followed by lot by lot reliability testing							
Design/Change Control	Required to inform customer of changes in: form fit function	AVX will qualify and notify customers before making any change to the following materials or processes: • Dielectric formulation, type, or supplier • Metal formulation, type, or supplier • Termination material formulation, type, or supplier • Manufacturing equipment type • Quality testing regime including sample size and accept/ reject criteria							







Parame	ter/Test	NP0 Specification Limits	Measuring Conditions Temperature Cycle Chamber									
	perature Range	-55°C to +125°C										
Capac	itance Q	Within specified tolerance <30 pF: Q≥ 400+20 x Cap Value ≥30 pF: Q≥ 1000	Freq.: 1.0 MHz ± 10% for cap ≤ 1000 pF 1.0 kHz ± 10% for cap > 1000 pF Voltage: 1.0Vrms ± .2V									
Insulation	Resistance	100,000MΩ or 1000MΩ - μF, whichever is less	Charge device with 60 ± 5 secs @ roon	rated voltage for								
Dielectric	: Strength	No breakdown or visual defects	Charge device with 300% of rated voltage for 1-5 seconds, w/charge and discharge current limited to 50 mA (max) Note: Charge device with 150% of rated voltage for 500V devices.									
	Appearance	No defects	Deflection	n: 2mm								
Resistance to	Capacitance Variation	±5% or ±.5 pF, whichever is greater	Test Time: 30									
Flexure Stresses	Q	Meets Initial Values (As Above)	To the second									
	Insulation Resistance	≥ Initial Value x 0.3	90 m									
Solder	rability	≥ 95% of each terminal should be covered with fresh solder	Dip device in eutectic for 5.0 ± 0.5									
	Appearance Capacitance	No defects, <25% leaching of either end terminal										
	Variation	≤ ±2.5% or ±.25 pF, whichever is greater	Die desies in some misse	-ld								
Resistance to Solder Heat	Q	Meets Initial Values (As Above)	Dip device in eutectic solder at 260°C for 60 seconds. Store at room temperature for 24 ± 2 hours before measuring electrical properties.									
	Insulation Resistance	Meets Initial Values (As Above)	nours before measuring	ciccincal properties.								
	Dielectric Strength	Meets Initial Values (As Above)										
	Appearance	No visual defects	Step 1: -55°C ± 2°	30 ± 3 minutes								
	Capacitance Variation	≤ ±2.5% or ±.25 pF, whichever is greater	Step 2: Room Temp	≤ 3 minutes								
Thermal Shock	Q	Meets Initial Values (As Above)	Step 3: +125°C ± 2°	30 ± 3 minutes								
	Insulation Resistance	Meets Initial Values (As Above)	Step 4: Room Temp ≤ 3 minutes									
	Dielectric Strength	Meets Initial Values (As Above)	Repeat for 5 cycles a 24 hours at room									
	Appearance	No visual defects										
	Capacitance Variation	≤ ±3.0% or ± .3 pF, whichever is greater	Charge device with twice chamber set at									
Load Life	Q	≥ 30 pF: Q≥ 350 ≥10 pF, <30 pF: Q≥ 275 +5C/2 <10 pF: Q≥ 200 +10C	for 1000 hour	rs (+48, -0).								
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	room temperatur before mea	e for 24 hours								
	Dielectric Strength	Meets Initial Values (As Above)	25.5.5 1116.	· · · y ·								
	Appearance	No visual defects										
	Capacitance Variation	≤ ±5.0% or ± .5 pF, whichever is greater	Store in a test chamber s									
Load Life Load Humidity	Q	≥ 30 pF: Q≥ 350 ≥10 pF, <30 pF: Q≥ 275 +5C/2 <10 pF: Q≥ 200 +10C	± 5% relative humidi (+48, -0) with rated Remove from chamb	voltage applied.								
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	room temperature for measu	24 ± 2 hours before								
	Dielectric Strength	Meets Initial Values (As Above)										







PREFERRED SIZES ARE SHADED

SIZE			06	03				0805	1206							
WVDC		16	25	50	100	16	25	50	100	16	25	50	100			
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(pF) 1.0	1R0															
1.2	1R2															
1.5	1R5															
1.8	1R8															
2.2	2R2															
2.7	2R7															
3.3	3R3															
3.9	3R9															
4.7	4R7															
5.6	5R6															
6.8	6R8															
8.2	8R2															
10	100															
12	120															
15	150															
18	180															
22	220															
27	270															
33	330															
39	390															
47	470															
56	560															
68	680															
82	820															
100	101															
120	121															
150	151															
180	181															
220	221															
270	271															
330 390	331 391															
470	471															
560	561				-											
680	681															
820	821															
1000	102															
1200	122															
1500	152															
WVDC	102	16	25	50	100	16	25	50	100	16	25	50	100			
SIZE		10		03	100	10		0805	10	1206						





Parame	ter/Test	X7R Specification Limits	Measuring (Conditions						
Operating Tem		-55°C to +125°C	Temperature C	ycle Chamber						
Сарас		Within specified tolerance ≤ 10% for ≥ 50V DC rating ≤ 12.5% for 25V DC rating ≤ 12.5% for 25V and 16V DC rating ≤ 12.5% for ≤ 10V DC rating	Freq.: 1.0 kHz ± 10% Voltage: 1.0Vrms ± .2V							
Insulation	Resistance	100,000MΩ or 1000MΩ - μF, whichever is less	Charge device with rated voltage for 120 ± 5 secs @ room temp/humidity							
Dielectric	Strength	No breakdown or visual defects	Charge device with 300% of rated voltage for 1-5 seconds, w/charge and discharge current limited to 50 mA (max) Note: Charge device with 150% of rated voltage for 500V devices.							
	Appearance	No defects	Deflectio	n: 2mm						
Resistance to	Capacitance Variation	≤ ±12%	Test Time: 3							
Flexure Stresses	Dissipation Factor	Meets Initial Values (As Above)	l v							
Insulation Resistance Solderability		≥ Initial Value x 0.3	90 r	mm —						
Solder	ability	≥ 95% of each terminal should be covered with fresh solder	Dip device in eutectic for 5.0 ± 0.5							
	Appearance	No defects, <25% leaching of either end terminal								
	Capacitance Variation	≤ ±7.5%								
Resistance to Solder Heat	Dissipation Factor	Meets Initial Values (As Above)	Dip device in eutectic solder at 260°C for 60 seconds. Store at room temperature for 24 ± 2							
Solder Heat	Insulation Resistance	Meets Initial Values (As Above)	hours before measuring	g electrical properties.						
	Dielectric Strength	Meets Initial Values (As Above)								
	Appearance	No visual defects	Step 1: -55°C ± 2°	30 ± 3 minutes						
	Capacitance Variation	≤ ±7.5%	Step 2: Room Temp	≤ 3 minutes						
Thermal Shock	Dissipation Factor	Meets Initial Values (As Above)	Step 3: +125°C ± 2°	30 ± 3 minutes						
o.i.ook	Insulation Resistance	Meets Initial Values (As Above)	Step 4: Room Temp	≤ 3 minutes						
	Dielectric Strength	Meets Initial Values (As Above)	Repeat for 5 cycles and measure after 24 ± 2 hours at room temperature							
	Appearance	No visual defects								
	Capacitance Variation	≤ ±12.5%	Charge device with 1.5 r test chamber set	at 125°C ± 2°C						
Load Life	Dissipation Factor	≤ Initial Value x 2.0 (See Above)	for 1000 hours (+48, -0)							
	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from test cha room temperature for	24 ± 2 hours before						
	Dielectric Strength	Meets Initial Values (As Above)	meası	g.						
	Appearance	No visual defects								
	Capacitance Variation	≤ ±12.5%	Store in a test chamber : ± 5% relative humid							
Load	Dissipation Factor	≤ Initial Value x 2.0 (See Above)	(+48, -0) with rated	d voltage applied.						
Humidity	Insulation Resistance	≥ Initial Value x 0.3 (See Above)	Remove from chamber temperature an	d humidity for						
	Dielectric Strength	Meets Initial Values (As Above)	24 ± 2 hours before measuring.							







PREFERRED SIZES ARE SHADED

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